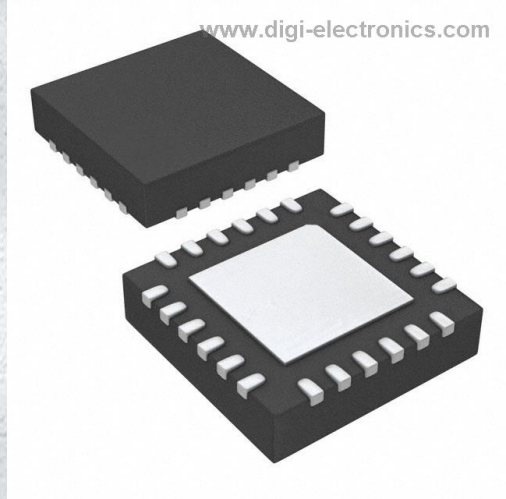
FXLH42245MPX Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number	FXLH42245MPX-DG
Manufacturer	onsemi
Manufacturer Product Number	FXLH42245MPX
Description	IC TRANSLTR BIDIRECTIONAL 24MLP
Detailed Description	Voltage Level Translator Bidirectional 1 Circuit 8 Channel 24-MLP (3.5x4.5)

Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
FXLH42245MPX	onsemi
Series:	Product Status:
-	Active
Translator Type:	Channel Type:
Voltage Level	Bidirectional
Number of Circuits:	Channels per Circuit:
1	8
Voltage - VCCA:	Voltage - VCCB:
1.1 V ~ 3.6 V	1.1 V ~ 3.6 V
Input Signal:	Output Signal:
-	-
Output Type:	Data Rate:
Tri-State, Non-Inverted	-
Operating Temperature:	Features:
-40°C ~ 85°C (TA)	Power-Off Protection
Mounting Type:	Package / Case:
Surface Mount	24-WFQFN Exposed Pad
Supplier Device Package:	Base Product Number:
24-MLP (3.5x4.5)	FXLH42245

Environmental & Export classification

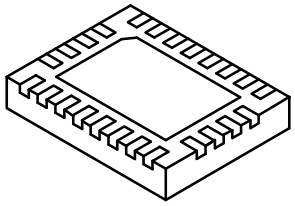
RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8542.39.0001	

onsemi

DATA SHEET
www.onsemi.com

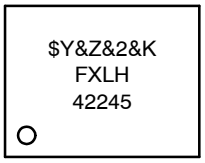
Low-Voltage, Dual-Supply, 8-Bit, Signal Translator with Configurable Voltage Supplies, Bushold Data Inputs, 3-State Outputs and 26 Ω Series Resistors in the B-Port Outputs

FXLH42245



WQFN24, 4.5 x 3.5, 0.5P
CASE 510CE

MARKING DIAGRAM



$Y	= **onsemi** logo
&Z	= Assembly Plant Code
&2	= 2−Digit Date Code
&K	= 2−Digits Lot Run Traceability Code
FXLH42245	= Specific Device Code

ORDERING INFORMATION

Device	Package	Shipping†
FXLH42245MPX	WQFN24 (Pb−Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

Description

The FXLH42245 is a configurable dual−voltage−supply translator designed for bi−directional voltage translation of signals between two voltage levels. The device allows translation between voltages as high as 3.6 V to as low as 1.1 V. The A port tracks the V_{CCA} level and the B port tracks the V_{CCB} level. Both ports are designed to accept supply voltage levels from 1.1 V to 3.6 V. This allows for bi−directional voltage translation over a variety of voltage levels: 1.2 V, 1.5 V, 1.8 V, 2.5 V, and 3.3 V.

The device remains in 3−state until both V_{CC}s reach active levels, allowing either V_{CC} to be powered−up first. The device also contains power−down control circuits that place the device in 3−state if either V_{CC} is removed.

The Transmit/Receive ($T/\overline{R}$) input determines the direction of data flow through the device. The $\overline{OE}$ input, when HIGH, disables both the A and B ports by placing them in a 3−state condition. The FXLH42245 is designed with the control pins ($T/\overline{R}$ and $\overline{OE}$) supplied by V_{CCA}.

Features

- Bi−Directional Interface between Two Levels from 1.1 V to 3.6 V
- Fully Configurable, Inputs Track V_{CC} Level
- Non−Preferential Power−Up; Either V_{CC} May Be Powered−Up First
- Outputs Remain in 3−State Until Active V_{CC} Level is Reached
- Outputs Switch to 3−State if Either V_{CC} is at GND
- Bushold on Data Inputs Eliminates the need for External Pull−Up / Pull−Down Resistors
- 26 Ω Output Series Resistors on the B Port to Reduce Line Noise
- Power−Off Protection
- Control Input ($T/\overline{R}$, $\overline{OE}$) Levels are Referenced to V_{CCA} Voltage
- Packaged in 24−Pin MLP
- ESD Protection Exceeds:
  - 4 kV Human Body Model (JESD22−A114 & Mil Std 883e 3015.7)
  - 8 kV Human Body Model I/O to GND (JESD22−A114 & Mil Std 883e 3015.7)
  - 1 kV Charge Device Model (ESD STM 5.3)
  - 200 V Machine Model (JESD22−A115 & ESD STM5.2)

FXLH42245

PIN CONFIGURATION

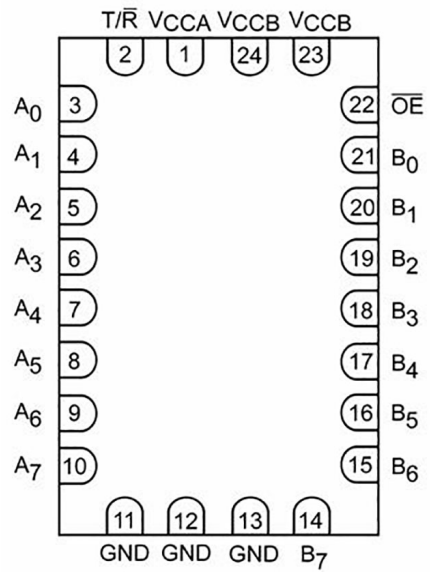


Figure 1. Pin Configuration (Top Through View)

PIN DEFINITIONS

Pin No.	Name	Description
1	V_{CCA}	Side−A Power Supply
2	T/$\overline{R}$	Transmit / Receive Input
3, 4, 5, 6, 7, 8, 9, 10	A_0, A_1, A_2, A_3, A_4, A_5, A_6, A_7	Side−A Inputs or 3−State Outputs
11, 12, 13	GND	Ground
14, 15, 16, 17, 18, 19, 20, 21	B_7, B_6, B_5, B_4, B_3, B_2, B_1, B_0	Side−B Inputs or 3−State Outputs
22	$\overline{OE}$	Output Enable Input
23, 24	V_{CCB}	Side−B Power Supply

TRUTH TABLE

Inputs		
$\overline{OE}$	T/$\overline{R}$	Description
LOW Voltage Level	LOW Voltage Level	Bus B Data to Bus A
LOW Voltage Level	HIGH Voltage Level	Bus A Date to Bus B
HIGH Voltage Level	Don't Care	3−State

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Condition		Min	Max	Unit
V_{CCA}	Supply Voltage			−0.5	4.6	V
V_{CCB}				−0.5	4.6	
V_I	DC Input Voltage	I/O Port A		−0.5	V_{CCA} + 0.5	V
		I/O Port B		−0.5	V_{CCB} + 0.5	
		Control Inputs (T/$\overline{R}$, $\overline{OE}$)		−0.5	4.6	
V_O	Output Voltage (Note 1)	Output 3−State		−0.5	4.6	V
		Output Active (A_n)		−0.5	V_{CCA} + 0.5	
		Output Active (B_n)		−0.5	V_{CCB} + 0.5	
I_{IK}	DC Input Diode Current	V_I < 0 V			−50	mA
I_{OK}	DC Output Diode Current	V_O < 0 V			−50	mA
		V_O > V_{CC}			50	
I_{OH}/I_{OL}	DC Output Source/Sink Current				±50	mA
I_{CC}	DC V_{CC} or Ground Current per Supply Pin				±100	mA
T_{STG}	Storage Temperature Range			−65	+150	°C
ESD	Electrostatic Discharge Capability	Human Body Model, JESD22−A114, Mil Std 883e 3015.7			4	kV
			I/O to GND		8	
		Charged Device Model, JESD22−C101, STM 5.3			1	
		Machine Model, JESD22−A115, STM 5.2			200	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. I/O absolute maximum ratings must be observed.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CC}	Power Supply	Operating V_{CCA} or V_{CCB}		1.1	3.6	V
V_I	Input Voltage	Port A		0	V_{CCA}	V
		Port B		0	V_{CCB}	
		Control Input (T/$\overline{R}$, $\overline{OE}$)		0	V_{CCA}	
I_{OH}/I_{OL}	Output Current	Port A V_{CCA}	3.0 V to 3.6 V		±24	mA
			2.3 V to 2.7 V		±18	
			1.65 V to 1.95 V		±6	
			1.40 V to 1.65 V		±2	
			1.1 V to 1.4. V		±0.5	
		Port B V_{CCB} Resistor Outputs	3.0 V to 3.6 V		±14	
			2.3 V to 2.7 V		±8	
			1.65 V to 1.95 V		±3	
			1.40 V to 1.65 V		±1	
			1.1 V to 1.4. V		±0.25	
T_A	Operating Temperature, Free Air			−40	+85	°C
$\Delta V/\Delta t$	Input Edge Rate	$V_{CCA/B}$ = 1.1 V to 3.6 V			10	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

2. All unused inputs must be held at V_{CCI} or GND.

ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Conditions	V_{CCI} (V)	V_{CCO} (V)	Min	Max	Unit
V_{IH}	HIGH Level Input (Note 3)	Data Inputs An, Bn	2.70 to 3.60	1.1 to 3.6	2.0	–	V
			2.30 to 2.70		1.6	–	
			1.65 to 2.30		0.65 x V_{CCI}	–	
			1.40 to 1.65		0.65 x V_{CCI}	–	
			1.10 to 1.40		0.9 x V_{CCI}	–	
		Control Pins $\overline{OE}$, T/$\overline{R}$ (Referenced to V_{CCA})	2.70 to 3.60	1.1 to 3.6	2.0	–	
			2.30 to 2.70		1.6	–	
			1.65 to 2.30		0.65 x V_{CCA}	–	
			1.40 to 1.65		0.65 x V_{CCA}	–	
			1.10 to 1.40		0.9 x V_{CCA}	–	
V_{IL}	LOW Level Input (Note 3)	Data Inputs An, Bn	2.70 to 3.60	1.1 to 3.6	–	0.8	V
			2.30 to 2.70		–	0.7	
			1.65 to 2.30		–	0.35 x V_{CCI}	
			1.40 to 1.65		–	0.35 x V_{CCI}	
			1.10 to 1.40		–	0.10 x V_{CCI}	
		Control Pins $\overline{OE}$, T/$\overline{R}$ (Referenced to V_{CCA})	2.70 to 3.60	1.1 to 3.6	–	0.8	
			2.30 to 2.70		–	0.7	
			1.65 to 2.30		–	0.35 x V_{CCA}	
			1.40 to 1.65		–	0.35 x V_{CCA}	
			1.10 to 1.40		–	0.10 x V_{CCA}	
V_{OH}	HIGH Level Output B Port (Note 4)	I_{OH} = −100 μA	1.1 to 3.6	1.1 to 3.6	V_{CC0} to 0.2	–	V
		I_{OH} = −6 mA	2.7	2.7	2.2	–	
		I_{OH} = −8 mA	3.0	3.0	2.4	–	
		I_{OH} = −12 mA	3.0	3.0	2.2	–	
		I_{OH} = −4 mA	2.3	2.3	2.0	–	
		I_{OH} = −6 mA	2.3	2.3	1.8	–	
		I_{OH} = −8 mA	2.3	2.3	1.7	–	
		I_{OH} = −3 mA	1.65	1.65	1.25	–	
		I_{OH} = −1 mA	1.4	1.4	1.05	–	
		I_{OH} = −0.25 mA	1.1	1.1	0.75 x V_{CC0}	–	
	HIGH Level Output A Port (Note 4)	I_{OH} = −100 μA	1.1 to 3.6	1.1 to 3.6	V_{CC0} to 0.2	–	
		I_{OH} = −12 mA	2.7	2.7	2.2	–	
		I_{OH} = −18 mA	3.0	3.0	2.4	–	
		I_{OH} = −24 mA	3.0	3.0	2.2	–	
		I_{OH} = −6 mA	2.3	2.3	2.0	–	
		I_{OH} = −12 mA	2.3	2.3	1.8	–	
		I_{OH} = −18 mA	2.3	2.3	1.7	–	
		I_{OH} = −6 mA	1.65	1.65	1.25	–	
		I_{OH} = −2 mA	1.4	1.4	1.05	–	
		I_{OH} = −0.5 mA	1.1	1.1	0.75 x V_{CC0}	–	

ELECTRICAL CHARACTERISTICS (continued)

Symbol	Parameter	Conditions	V_{CCI} (V)	V_{CCO} (V)	Min	Max	Unit
V_{OL}	LOW Level Output B Port (Note 4)	I_{OH} = 100 μA	1.1 to 3.6	1.1 to 3.6	–	0.2	V
		I_{OH} = 6 mA	2.7	2.7	–	0.4	
		I_{OH} = 8 mA	3.0	3.0	–	0.55	
		I_{OH} = 12 mA	3.0	3.0	–	0.80	
		I_{OH} = 6 mA	2.3	2.3	–	0.4	
		I_{OH} = 8 mA	2.3	2.3	–	0.6	
		I_{OH} = 3 mA	1.65	1.65	–	0.3	
		I_{OH} = 1 mA	1.4	1.4	–	0.35	
		I_{OH} = 0.25 mA	1.1	1.1	–	0.3 x V_{CC0}	
	LOW Level Output A Port (Note 4)	I_{OH} = 100 μA	1.1 to 3.6	1.1 to 3.6	–	0.2	
		I_{OH} = 12 mA	2.7	2.7	–	0.4	
		I_{OH} = 18 mA	3.0	3.0	–	0.4	
		I_{OH} = 24 mA	3.0	3.0	–	0.55	
		I_{OH} = 12 mA	2.3	2.3	–	0.4	
		I_{OH} = 18 mA	2.3	2.3	–	0.6	
		I_{OH} = 6 mA	1.65	1.65	–	0.3	
		I_{OH} = 2 mA	1.4	1.4	–	0.35	
		I_{OH} = 0.5 mA	1.1	1.1	–	0.3 x V_{CC0}	
I_L	Input Leakage Current, Control Pins	V_I = V_{CCA} or GND	1.1 to 3.6	3.6	–	±1.0	μA
$I_{I(HOLD)}$	Bushold Input Minimum Drive Current	V_{IN} = 0.8	3.0	3.0	75	–	μA
		V_{IN} = 2.0	3.0	3.0	−75	–	
		V_{IN} = 0.7	2.3	2.3	45	–	
		V_{IN} = 1.6	2.3	2.3	−45	–	
		V_{IN} = 0.57	1.65	1.65	25	–	
		V_{IN} = 10.7	1.65	1.65	−25	–	
		V_{IN} = 0.49	1.4	1.4	11	–	
		V_{IN} = 0.91	1.4	1.4	−11	–	
		V_{IN} = 0.11	1.1	1.1	–	4	
		V_{IN} = 0.99	1.1	1.1	–	−4	
$I_{I(OD)}$	Bushold Input Over−Drive Current−to−Current State	(Note 5)	3.6	3.6	450	–	μA
		(Note 6)	3.6	3.6	−450	–	
		(Note 5)	2.7	2.7	300	–	
		(Note 6)	2.7	2.7	−300	–	
		(Note 5)	1.95	1.95	200	–	
		(Note 6)	1.95	1.95	−200	–	
		(Note 5)	1.6	1.6	120	–	
		(Note 6)	1.6	1.6	−120	–	
		(Note 5)	1.4	1.4	80	–	
		(Note 6)	1.4	1.4	−80	–	

ELECTRICAL CHARACTERISTICS (continued)

Symbol	Parameter	Conditions	V_{CCI} (V)	V_{CCO} (V)	Min	Max	Unit
I_{OFF}	Power Off Leakage Current	A_n, V_I or V_O = 0 V to 3.6 V	0	3.6	–	±10	μA
		B_n, V_I or V_O = 0 V to 3.6 V	3.6	0	–	±10	
I_{OZ}	3−State Output Leakage (V_O, V_{CC} or GND V_I = V_{IH} or V_{IL})	A_n, B_n, $\overline{OE}$ = V_{IH}	3.6	3.6	–	±10	μA
		Bn, $\overline{OE}$ = Don't Care (Note 7)	0	3.6	–	±10	
		An, $\overline{OE}$ = Don't Care (Note 7)	3.6	0	–	±10	
$I_{CCA/B}$	Quiescent Supply Current (Note 8)	V_I = V_{CCI} or GND; I_O = 0	1.1 to 3.6	1.1 to 3.6	–	20	μA
I_{CCZ}			1.1 to 3.6	1.1 to 3.6	–	20	μA
I_{CCA}		V_I = V_{CCA} or GND; I_O = 0	0	1.1 to 3.6	–	−10	μA
			1.1 to 3.6	0	–	10	
I_{CCB}		V_I = V_{CCB} or GND; I_O = 0	1.1 to 3.6	0	–	−10	μA
			0	1.1 to 3.6	–	10	
$\Delta I_{CCA/B}$	Increase in I_{CC} per Input; Other Inputs at V_{CC} or GND	V_{IH} = 3.0	3.6	3.6	–	500	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. V_{CCI} = the V_{CC} associated with the data input under test.
4. V_{CCO} = the VCC associated with the output under test.
5. An external driver must source at least the specified current to switch LOW−to−HIGH.
6. An external driver must source at least the specified current to switch HIGH−to−LOW.
7. Don't care = any valid logic level.
8. Reflects current per supply, V_{CCA} or V_{CCB}.

AC ELECTRICAL CHARACTERISTICS

V_{CCA} = 3.0 V to 3.6 V

		T_A = −40°C to +85°C										
		V_{CCB} = 3.0 V to 3.6 V		V_{CCB} = 2.3 V to 2.7 V		V_{CCB} = 1.65 V to 1.95 V		V_{CCB} = 1.4 V to 1.6 V		V_{CCB} = 1.1 V to 1.3 V		
Symbol	Parameter	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Unit
t_{PLH}, t_{PHL}	Propagation Delay A to B	0.5	3.9	0.5	4.5	0.9	5.9	1.0	7.4	1.6	22.0	ns
	Propagation Delay B to A	0.2	3.5	0.2	3.8	0.3	4.0	0.5	4.3	0.8	13.0	
t_{PZL}, t_{PZH}	Output Enable $\overline{OE}$−to−B	0.7	4.8	1.0	5.1	1.5	6.7	1.5	7.1	2.0	18.0	ns
	Output Enable $\overline{OE}$−to−A	0.5	4.0	0.5	4.0	0.5	4.0	0.5	4.0	0.5	4.0	
t_{PHZ}, t_{PZL}	Output Enable $\overline{OE}$−to−B	0.4	4.3	0.4	4.4	0.9	5.2	1.7	6.8	2.0	19.0	ns
	Output Enable $\overline{OE}$−to−A	0.2	3.7	0.2	3.7	0.2	3.7	0.2	3.7	0.2	3.7	

AC ELECTRICAL CHARACTERISTICS (continued)

V_{CCA} = 2.3 V to 2.7 V

Symbol	Parameter	T_A = −40°C to +85°C										Unit
		V_{CCB} = 3.0 V to 3.6 V		V_{CCB} = 2.3 V to 2.7 V		V_{CCB} = 1.65 V to 1.95 V		V_{CCB} = 1.4 V to 1.6 V		V_{CCB} = 1.1 V to 1.3 V		
		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
t_{PLH}, t_{PHL}	Propagation Delay A to B	0.5	4.3	0.6	4.8	0.9	6.0	1.0	7.6	1.6	22.0	ns
	Propagation Delay B to A	0.3	3.9	0.4	4.2	0.5	4.5	0.5	4.8	1.0	7.0	
t_{PZL}, t_{PZH}	Output Enable $\overline{OE}$–to–B	0.8	5.1	1.0	5.5	1.5	6.9	1.5	7.4	2.0	19.0	ns
	Output Enable $\overline{OE}$–to–A	0.6	4.5	0.6	4.5	0.6	4.5	0.6	4.5	0.6	4.5	
t_{PHZ}, t_{PZL}	Output Enable $\overline{OE}$–to–B	0.4	4.6	0.4	4.8	0.9	5.3	1.7	7.1	2.0	19.0	ns
	Output Enable $\overline{OE}$–to–A	0.2	4.0	0.2	4.0	0.2	4.0	0.2	4.0	0.2	4.0	

V_{CCA} = 1.65 V to 1.95 V

Symbol	Parameter	T_A = −40°C to +85°C										Unit
		V_{CCB} = 3.0 V to 3.6 V		V_{CCB} = 2.3 V to 2.7 V		V_{CCB} = 1.65 V to 1.95 V		V_{CCB} = 1.4 V to 1.6 V		V_{CCB} = 1.1 V to 1.3 V		
		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
t_{PLH}, t_{PHL}	Propagation Delay A to B	0.5	4.6	0.7	5.1	1.1	6.2	1.1	7.8	1.7	22.0	ns
	Propagation Delay B to A	0.5	5.4	0.5	5.6	0.8	5.7	1.0	6.0	1.2	8.0	
t_{PZL}, t_{PZH}	Output Enable $\overline{OE}$–to–B	0.8	5.4	1.0	5.9	1.5	7.3	1.5	7.7	2.0	20.0	ns
	Output Enable $\overline{OE}$–to–A	1.0	6.7	1.0	6.7	1.0	6.7	1.0	6.7	1.0	6.7	
t_{PHZ}, t_{PZL}	Output Enable $\overline{OE}$–to–B	0.4	4.7	0.4	4.9	1.0	5.4	1.7	7.2	2.0	19.0	ns
	Output Enable $\overline{OE}$–to–A	0.5	5.0	0.5	5.0	0.5	5.0	0.5	5.0	0.5	5.0	

AC ELECTRICAL CHARACTERISTICS (continued)

V_{CCA} = 1.4 V to 1.6 V

		T_A = −40°C to +85°C										
		V_{CCB} = 3.0 V to 3.6 V		V_{CCB} = 2.3 V to 2.7 V		V_{CCB} = 1.65 V to 1.95 V		V_{CCB} = 1.4 V to 1.6 V		V_{CCB} = 1.1 V to 1.3 V		
Symbol	Parameter	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Unit
t_{PLH}, t_{PHL}	Propagation Delay A to B	0.7	4.8	0.8	5.3	1.2	6.4	1.3	7.9	1.7	22.0	ns
	Propagation Delay B to A	0.6	6.8	0.8	6.9	0.9	7.1	1.0	7.3	1.2	9.5	
t_{PZL}, t_{PZH}	Output Enable $\overline{OE}$–to–B	1.1	5.8	1.3	6.3	1.5	7.8	2.0	8.1	2.0	20.0	ns
	Output Enable $\overline{OE}$–to–A	1.0	7.5	1.0	7.5	1.0	7.5	1.0	7.5	1.0	7.5	
t_{PHZ}, t_{PZL}	Output Enable $\overline{OE}$–to–B	0.6	4.8	0.6	5.1	1.1	5.8	2.0	7.7	2.0	18.0	ns
	Output Enable $\overline{OE}$–to–A	1.0	6.0	1.0	6.0	1.0	6.0	1.0	6.0	0.5	6.0	

V_{CCA} = 1.1 V to 1.3 V

		T_A = −40°C to +85°C										
		V_{CCB} = 3.0 V to 3.6 V		V_{CCB} = 2.3 V to 2.7 V		V_{CCB} = 1.65 V to 1.95 V		V_{CCB} = 1.4 V to 1.6 V		V_{CCB} = 1.1 V to 1.3 V		
Symbol	Parameter	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Unit
t_{PLH}, t_{PHL}	Propagation Delay A to B	1.0	13.8	1.0	7.8	1.0	8.4	1.0	10.4	2.0	24.0	ns
	Propagation Delay B to A	1.4	22.0	1.4	22.0	1.5	22.0	1.5	22.0	2.0	24.0	
t_{PZL}, t_{PZH}	Output Enable $\overline{OE}$–to–B	1.5	12.6	1.5	9.6	1.5	10.6	2.0	11.6	2.0	24.0	ns
	Output Enable $\overline{OE}$–to–A	2.0	22.0	2.0	22.0	2.0	22.0	2.0	22.0	2.0	22.0	
t_{PHZ}, t_{PZL}	Output Enable $\overline{OE}$–to–B	1.2	15.0	0.9	7.6	1.2	8.6	2.0	10.6	3.0	21.0	ns
	Output Enable $\overline{OE}$–to–A	2.0	15.0	2.0	12.0	2.0	12.0	2.0	12.0	2.0	12.0	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

CAPACITANCE

Symbol	Parameter	Conditions	Typical (T_A = 25°C)	Unit
C_{IN}	Input Capacitance Control Pins ($\overline{OE}$, T/$\overline{R}$)	V_{CCA} = V_{CCB} = 3.3 V, V_I = 0 V or $V_{CCA/B}$	4	pF
$C_{I/O}$	Input / Output Capacitance A_n, B_n Port	V_{CCA} = V_{CCB} = 3.3 V, V_I = 0 V or $V_{CCA/B}$	5	pF
C_{PD}	Power Dissipation Capacitance	V_{CCA} = V_{CCB} = 3.3 V, V_I = 0 V or V_{CC}, f = 10 MHz	20	pF

AC LOADINGS AND WAVEFORMS

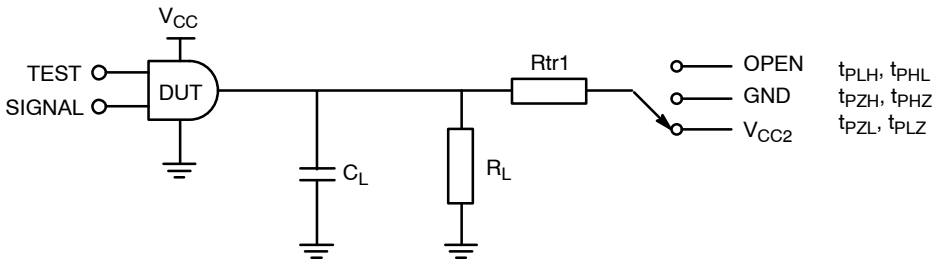


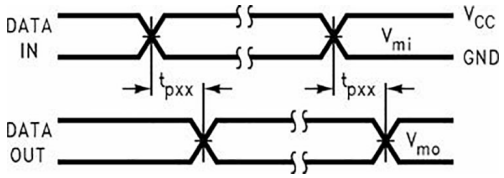
Figure 2. AC Test Circuit

Table 1. TEST CIRCUIT PARAMETERS

Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PLZ}, t_{PZL}	V_{CC0} • 2 at V_{CC0} = 3.3 + 0.3 V, 2.5 V + 0.2 V, 1.8 V + 0.15 V, 1.5 V + 0.1 V, 1.2 V + 0.1 V
t_{PHZ}, t_{PZH}	GND

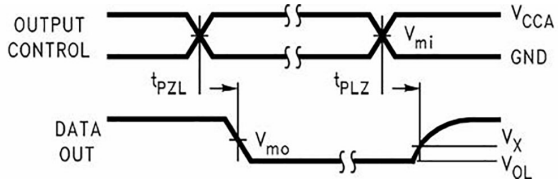
Table 2. AC LOAD TABLE

V_{CC0}	C_L	R_L	Rtr1
1.2 V ± 0.1 V	15 pF	2 kΩ	2 kΩ
1.5 V ± 0.1 V	15 pF	2 kΩ	2 kΩ
1.8 V ± 0.15 V	30 pF	500 Ω	500 Ω
2.5 V ± 0.2 V	30 pF	500 Ω	500 Ω
3.3 V ± 0.3 V	30 pF	500 Ω	500 Ω



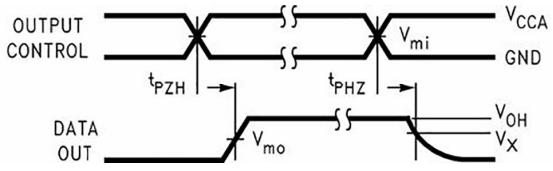
9. Input $t_R = t_F$ = 2.0 ns, 10% to 90%

Figure 3. Waveform for Inverting and Non–Inverting Functions



10. Input $t_R = t_F$ = 2.0 ns, 10% to 90%

Figure 4. 3–State Output High Enable and Disable for Low Voltage Logic



11. Input $t_R = t_F$ = 2.0 ns, 10% to 90%

Figure 5. 3–State Output High Enable and Disable for Low Voltage Logic

Table 3.

Symbol	V_{CC}				
	3.3 V ± 0.3 V	**2.5 V ± 0.2 V**	**1.8 V ± 0.15 V**	**1.5 V ± 0.1 V**	**1.2 V ± 0.1 V**
V_{MI}	$V_{CCI}/2$	$V_{CCI}/2$	$V_{CCI}/2$	$V_{CCI}/2$	$V_{CCI}/2$
V_{MO}	$V_{CCO}/2$	$V_{CCO}/2$	$V_{CCO}/2$	$V_{CCO}/2$	$V_{CCO}/2$
V_X	V_{OH} − 0.3 V	V_{OH} − 0.15 V	V_{OH} − 0.15 V	V_{OH} − 0.1 V	V_{OH} − 0.1 V
V_Y	V_{OL} + 0.3 V	V_{OL} + 0.15 V	V_{OL} + 0.15 V	V_{OL} + 0.1 V	V_{OL} + 0.1 V

12. For V_{MI} V_{CCO} = V_{CCA} for control pins T/$\overline{R}$ and $\overline{OE}$ or $V_{CCA}/2$.

FUNCTIONAL DESCRIPTION

Power−Up/Power−Down Sequencing

FXL translators offer an advantage in that either VCC may be powered up first. This benefit derives from the chip design. When either V_{CC} is at 0 V, outputs are in a High−impedance state. The control inputs (T/$\overline{R}$ and $\overline{OE}$) are designed to track the V_{CCA} supply. A pull−up resistor tying $\overline{OE}$ to V_{CCA} should be used to ensure that bus contention, excessive currents, or oscillations do not occur during power−up/power−down. The size of the pull−up resistor is based upon the current−sinking capability of the OE driver.

The recommended power−up sequence is:

1. Apply power to either V_{CC}.
2. Apply power to the T/$\overline{R}$ input (logic HIGH for A−to−B operation; logic LOW for B−to−A operation) and to the respective data inputs (A port or B port). This may occur at the same time as step 1.
3. Apply power to the other V_{CC}.
4. Drive the $\overline{OE}$ input LOW to enable the device.

The recommended power−down sequence is:

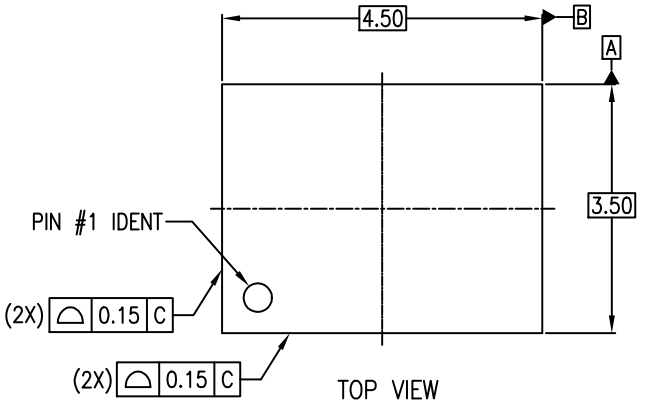
1. Drive $\overline{OE}$ input HIGH to disable the device.
2. Remove power from either V_{CC}.
3. Remove power from the other V_{CC}.

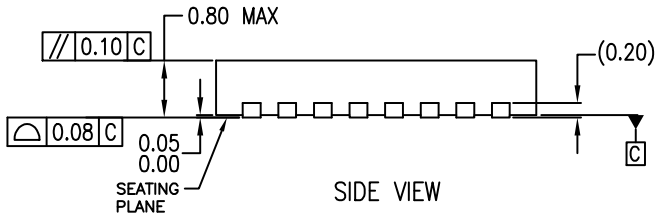
onsemi

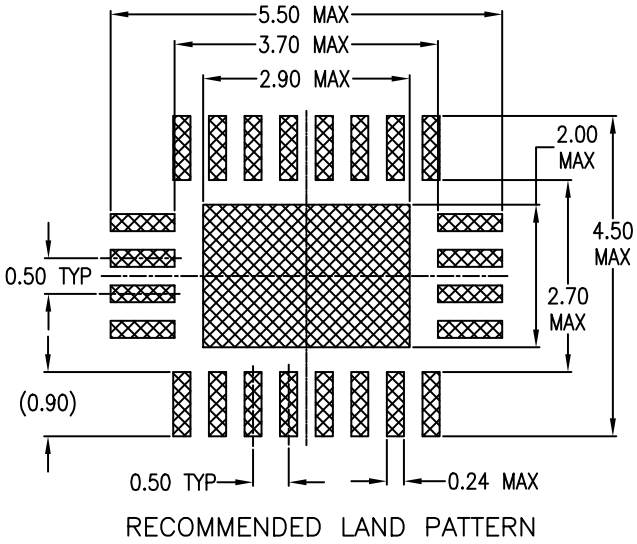
MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

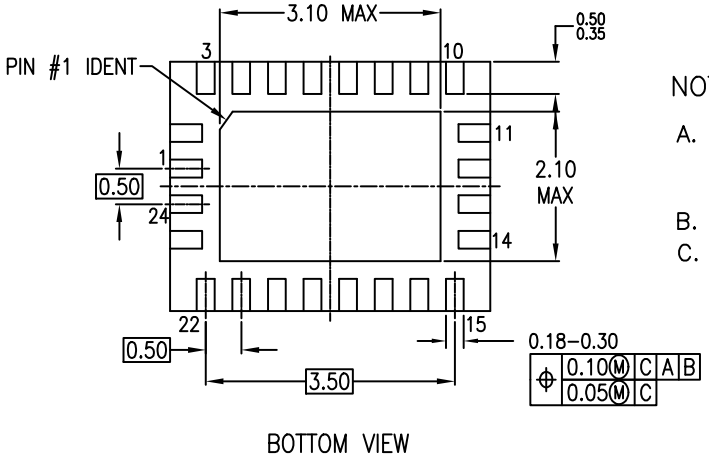
WQFN24 4.5x3.5, 0.5P
CASE 510CE
ISSUE O

DATE 31 AUG 2016









NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO–220, VARIATION WFSD–2 FOR DIMENSIONS ONLY. PIN NUMBERING DOES NOT COMPLY.
B. DIMENSIONS ARE IN MILLIMETERS.
C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994

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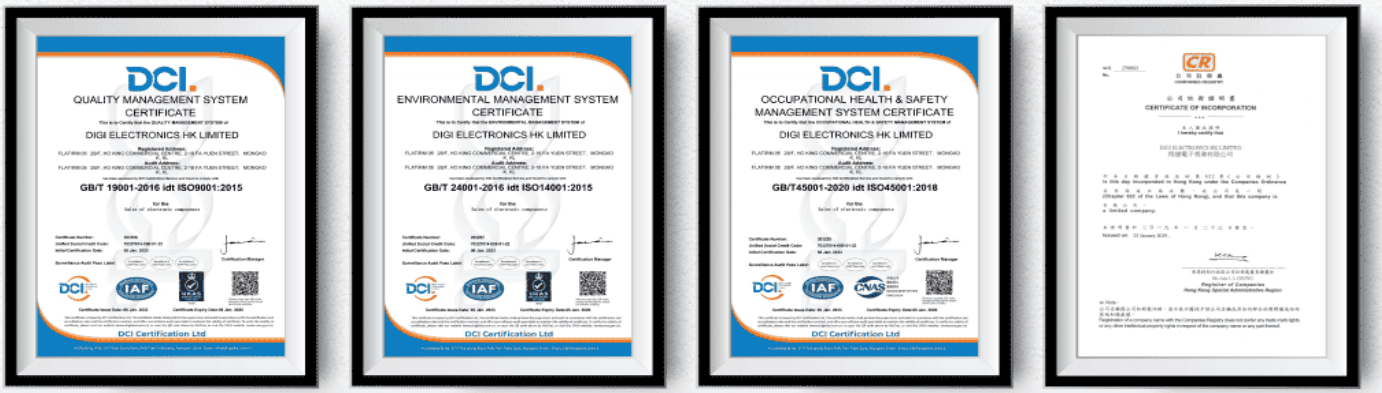

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